Vishay Semiconductors

Schottky Rectifier, 3.0 A

Cathode

Anode

-0

SMC

3 A

15 V

0.3 V

50 mA at 100 °C

125 °C

Single die

1.5 mJ



- 125 °C T_J operation (V_B < 5 V)
- Optimized for OR-ing applications
- Ultralow forward voltage drop
- · High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC
- · Designed and qualified for industrial level

DESCRIPTION

The VS-30BQ015PbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	3.0	A		
V _{RRM}		15	V		
I _{FSM}	t _p = 5 μs sine	650	A		
V _F	1.0 Apk, T _J = 75 °C	0.30	V		
TJ	Range	- 55 to 125	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-30BQ015PbF	UNITS	
Maximum DC reverse voltage	V _R	15	V	
Maximum working peak reverse voltage	V _{RWM}	25	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Manian and a survey of family and a survey of	I _{F(AV)}	50 % duty cycle at T_L = 83 °C, rectangular waveform		3.0	
Maximum average forward current		50 % duty cycle at T_L = 78 °C, rectangular waveform		4.0	
Maximum peak one cycle non-repetitive surge current	I _{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	650	A
		10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	75	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 0.5 A, L = 12 mH		1.5	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _B typical		0.5	А





SMC

PRODUCT SUMMARY

Package

I_{F(AV)}

 V_{R} V_F at I_F

I_{RM}

T_J max.

Diode variation

 E_{AS}

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop		3 A	T 05 %0	0.35	V
	V _{FM} ⁽¹⁾	6 A	T _J = 25 °C	0.35 0.40 0.30 0.35 4 50 25 °C 1120	
	VFM (')	3 A	T 75 %O		
		6 A	T _J = 75 °C		
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C		4	mA
	IRM ("	T _J = 100 °C	V _R = Rated V _R	50	
Maximum junction capacitance	C _T	$V_{\rm R}$ = 5 $V_{\rm DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		1120	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		3.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 $\,\%$

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range	T _J ⁽¹⁾		- 55 to 125	°C
Maximum storage temperature range	T _{Stg}		- 55 to 150	
Maximum thermal resistance, junction to lead	R _{thJL} ⁽²⁾		12	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	46	
Approximate weight			0.24	g
			0.008	oz.
Marking device		Case style SMC (similar to DO-214AB)	V3C	

Notes

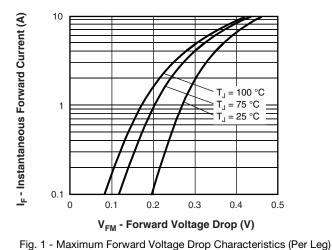
(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

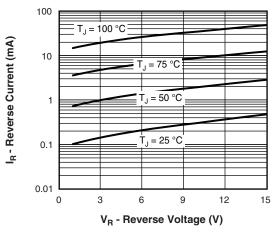
⁽²⁾ Mounted 1" square PCB

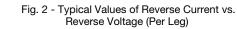


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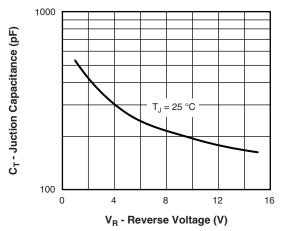


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

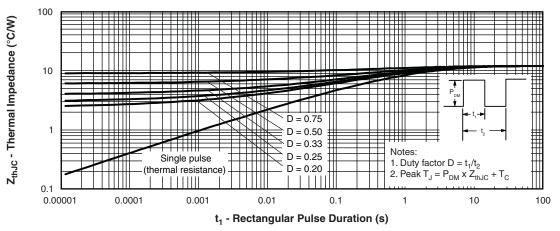
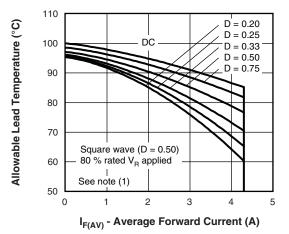


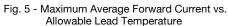
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

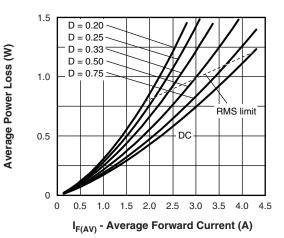
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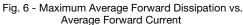
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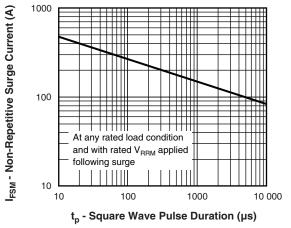


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

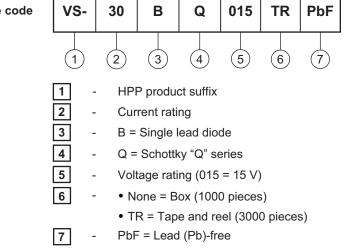


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ORDERING INFORMATION TABLE

Device code



LINKS TO RELATED DOCUMENTS			
Dimensions		www.vishay.com/doc?95023	
Part marking information		www.vishay.com/doc?95029	
Deckeding information	Tape and reel	www.vishay.com/doc?95034	
Packaging information	Bulk	www.vishay.com/doc?95397	
SPICE model		www.vishay.com/doc?95439	

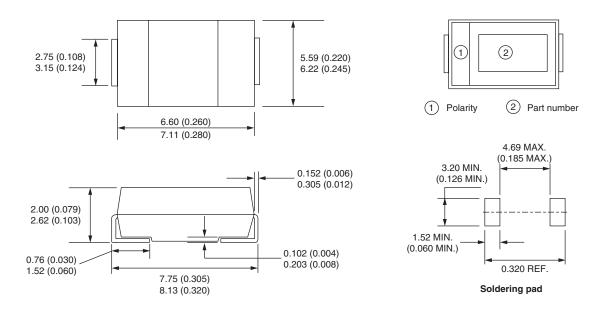


Outline Dimensions

Vishay High Power Products

SMC

DIMENSIONS in millimeters (inches)



1



Vishay

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